NSN 5962-01-121-1208

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View Online at https://aerobasegroup.com/nsn/5962-01-121-1208

Body Length:
0.785 inches
Body Width:
0.302 inches
Body Height:
0.175 inches
Maximum Power Dissipation Rating:
512.0 milliwatts
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and monolithic and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Current Rating Per Characteristic:
120.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Capitance Rating Per Characteristic:
5.00 input picofarads and 8.00 output picofarads
Time Rating Per Chacteristic:
50.00 nanoseconds access
Memory Device Type:
Prom
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:
 Demilitarization:
Yes - demil/mli

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